Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Ceramic and metal

# **Overall Length:**

Between 4.83 millimeters and 5.33 millimeters

# **Overall Diameter:**

Between 1.98 millimeters and 2.13 millimeters

# End Application:

Support equipment, t-37 aircraft; aircraft, phantom f-4; support equipment, t-38 aircraft; aircraft, freedom fighter f-5; aircraft. Eagle f-15

# Mounting Method:

Press fit

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

4.0 breakdown voltage, dc

Power Rating Per Characteristic:

250.0 milliwatts small-signal output power, common-base minor and 1.0 watts pulse rf power

## Capacitance Rating In Picofarads:

0.1

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Special Features:**

Weapon system essential

### **Precious Material And Location:**

Contact studs plated gold

### **Precious Material:**

Gold

### Terminal Type And Quantity:

2 case

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

## Fiig:

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